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# MAGNETISM AND FERROELECTRICITY

# Magnetic Properties of $Fe_xMn_{1-x}S$ Sulfides Exhibiting the Magnetoresistive Effect

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**Abstract**—The magnetic, electrical, and thermal (derived from DTA data) properties of  $Fe_xMn_{1-x}S$  polycrystalline sulfides ( $0 \le x \le 0.38$ ) synthesized based on  $\alpha$ -MnS (NaCl cubic lattice) and exhibiting colossal magnetoresistance were studied. The studies were conducted at temperatures from 77 to 1000 K and magnetic fields of up to 30 kOe. As the degree of cation substitution in the  $Fe_xMn_{1-x}S$  system was increased, the magnetic order was found to change from antiferromagnetic to ferromagnetic. In the high-temperature domain (550–850 K), the samples undergo two phase transitions with critical temperatures  $T_{c_1}$  and  $T_{c_2}$ , which are accompanied by reversible anomalies in the magnetization and thermal (DTA) properties and by a semiconductor–metal transition. © 2002 MAIK "Nauka/Interperiodica".

### 1. INTRODUCTION

The colossal magnetoresistance (CMR) remains an intriguing problem, because a clear understanding of the mechanism of this phenomenon is still lacking. The CMR effect has been revealed recently [1, 2] in new, NaCl-type cubic fcc compounds synthesized on the basis of manganese monosulfide. Materials with a NaCl lattice exhibiting CMR can be exemplified by cation-substituted systems based on europium oxide and chalcogenides [3]. In these compounds, CMR is observed to occur at low temperatures,  $\leq 40$  K. In the Fe<sub>x</sub>Mn<sub>1-x</sub>S sulfides, negative colossal magnetoresistance is found at temperatures  $T \leq 200$  K. A possible origin of the CMR is the magnetic and electronic separation of crystallographically similar compounds [2, 3].

#### 2. EXPERIMENTAL TECHNIQUES

The present communication reports on a study of the electrical, magnetic, and thermal (derived from DTA measurements) properties of polycrystalline sulfides  $Fe_xMn_{1-x}S$  with compositions  $0 \le x \le 0.38$  at temperatures from 77 to 1000 K in magnetic fields of up to 30 kOe. The techniques used to prepare the compounds and to measure their electrical properties are described elsewhere [1, 2]. The magnetic measurements in the range 100–1000 K and in fields of up to 10 kOe were performed using the Faraday method on samples placed in evacuated quartz ampoules. Measurements of the magnetic properties within the 77- to 300-K temperature interval and in fields up to 30 kOe were made in a vibrating-sample, superconducting-coil magnetometer.

X-ray structural measurements of the  $\text{Fe}_x \text{Mn}_{1-x} S$  samples thus synthesized ( $0 \le x \le 0.38$ ) showed them to be solid solutions with a NaCl-type structure typical of manganese monosulfide [1, 2]. The fcc lattice parameter decreases as the degree of cation substitution (*x*) increases, which agrees with the data from [4].

#### 3. EXPERIMENTAL RESULTS AND DISCUSSION

Figure 1 displays temperature dependences of the magnetization (measured in a field of 8.6 kOe) of single-crystal  $\alpha$ -MnS (curve 1) and polycrystalline  $\alpha$ -MnS (curve 2). The magnetic susceptibility of the polycrystalline manganese monosulfide,  $\chi_{300 \text{ K}} = 6.9 \times$  $10^{-5}$  cm<sup>3</sup>/g, is in agreement with the data from [5, 6] and is higher than that of the single-crystal compound. In the region of the Néel temperature  $T_N \sim 150$  K, the temperature-dependent magnetization exhibits a maximum which signals an antiferromagnetic transition. Above the Néel temperature, the inverse magnetic susceptibility  $\chi^{-1}(T)$  of the manganese monosulfide follows the Curie-Weiss relation, with the paramagnetic temperature  $\Theta$  and Curie constant C equal to -450 K and 4.32, respectively. At temperatures above ~450 K, the inverse magnetic susceptibility is seen to deviate from the Curie–Weiss law. According to [7], in this temperature interval, the charge carriers in  $\alpha$ -MnS reverse sign. For T < 450 K, the manganese monosulfide behaves as a *p*-type semiconductor, with the carrier mobility being  $\mu \sim 0.065 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ . For T > 450 K, the carriers are electrons and their mobility increases by an



**Fig. 1.** Temperature dependences of the magnetization of the Fe<sub>x</sub>Mn<sub>1-x</sub>S system measured in a field H = 8.6 kOe for different compositions *x*: (1) 0,  $\alpha$ -MnS single crystal; (2) 0, polycrystalline  $\alpha$ -MnS; (3) 0.05; (4) 0.15; (5) 0.25; (6) 0.29; (7) 0.27; (8) 0.32; and (9) 0.38. Inset: differential thermal analysis data for  $x \sim 0.35$ .

order of magnitude. Measurements of the temperature dependence of the magnetization of the cation-substituted  $Fe_xMn_{1-x}S$  samples revealed (Fig. 1) that, at low concentrations ( $x \le 0.2$ ), sulfides (similar to manganese monosulfide) undergo an antiferromagnet-paramagnet transition at low temperatures, with the Néel temperature increasing from 150 K (x = 0) to 185 ± 5 K ( $x \sim$ 0.2). The behavior of the magnetization  $\sigma(T)$  of samples with  $x \sim 0.2$  depends on the way in which the sample was cooled, namely, in a nonzero or zero magnetic field (Fig. 2). At  $T > T_N$ , the magnetic properties of cation-substituted samples with compositions  $0.05 \le x \le$ 0.2 behave similarly to  $\chi^{-1}(T)$  of manganese monosulfide. The temperature dependence of the inverse magnetic susceptibility  $\chi^{-1}(T)$  is described by the Curie– Weiss law, with the paramagnetic temperature  $\Theta$  and the Curie constant C increasing to -400 and 10.8 K  $(x \sim 0.2)$ , respectively. For temperatures T > 450 K, samples with  $0.05 \le x \le 0.2$  exhibit a deviation from the Curie–Weiss relation. More specifically, the magnetization (Fig. 1) displays an anomaly at a temperature  $T_{c_1}$ , which grows from 500 for  $x \sim 0.05$  to 580 K for  $x \sim 0.2$ . For compositions with  $x \sim 0.25$ , the behavior of the



**Fig. 2.** Temperature dependence of the magnetization of  $Fe_{0.2}Mn_{0.8}S$  cooled (1) in a zero magnetic field and (2) in a field H = 2 kOe. Inset: temperature dependence of inverse magnetic susceptibility for  $Fe_{0.25}Mn_{0.75}S$ .

inverse magnetic susceptibility  $\chi^{-1}(T)$  in the high-temperature domain is similar to that characteristic of ferrimagnets (see inset to Fig. 2) [8]. The paramagnetic Curie temperature assumes positive values ( $\Theta \sim 106$  K for  $x \sim 0.25$ ). The Curie constant becomes smaller, which indicates a decrease in the effective paramagnetic moment (for  $x \sim 0.25$ , C = 1.69). As seen from Fig. 1, the temperature dependences of the magnetization measured on samples with  $0.27 \le x \le 0.38$  in the range 100-1000 K in a field of 8.6 kOe are typical of ferromagnetic compounds. Below ~200 K, the magnetization of these samples decreases with decreasing temperature. In the high-temperature region, the  $\sigma(T)$ curve exhibits two magnetization anomalies at the critical temperatures  $T_{c_1}$  and  $T_{c_2}$ , which are accompanied by anomalies in the thermal (DTA) properties (inset to Fig. 1), thus indicating the occurrence of two phase transitions. At  $T_{c_1} \sim 550-650$  K, in the region of the reversible thermal (derived from DTA data) anomaly, there are anomalies in the electrical resistivity (Fig. 3) and in the fcc lattice parameter [9]. Below  $T_{c_1}$ , the resistivity behaves in a manner typical of the Fermi



**Fig. 3.** Temperature dependences of the electrical resistivity of the Fe<sub>x</sub>Mn<sub>1-x</sub>S system for different compositions *x*: (1) 0, (2) 0.3, (3) 0.33, (4) 0.36, (5) 0.4, and (6) 0.5.

glass state and of systems with Anderson localization [10]. The temperature  $T_{c_2}$  is the Curie point of sulfides; this temperature increases with increasing concentration *x* from 730 ( $x \sim 0.27$ ) to 860 K ( $x \sim 0.38$ ). As seen from Fig. 1, the magnetization of the high-temperature paramagnetic phase ( $T > T_{c_2}$ ) of the cation-substituted Fe<sub>x</sub>Mn<sub>1-x</sub>S samples is close to that of the paramagnetic phase of single-crystal  $\alpha$ -MnS and, for compositions with  $x \sim 0.27$ , 0.29, and 0.38, virtually does not depend on temperature. According to electrical resistivity measurements, the ferromagnet–paramagnet transition near  $T_{c_2}$  is accompanied by a semiconductor–metal change in the conduction character (Fig. 3).

At room temperature, the manganese monosulfide  $\alpha$ -MnS is in the paramagnetic state, in which the  $\sigma(H)$ relation is linear (Fig. 4). The  $\sigma(H)$  relations for the cation-substituted  $\text{Fe}_{x}\text{Mn}_{1-x}\text{S}$  solid solutions (0.05  $\leq x \leq$ 0.2) measured at room temperature become nonlinear [6], with no hysteresis in the field dependence of the magnetization. As the degree of cation substitution xincreases, the ferromagnetic contribution to magnetization increases and samples with x > 0.2 exhibit a magnetization hysteresis (Fig. 4), with the coercive force  $H_c$ increasing from 0.8 (x = 0.25) to 1.2 kOe (x = 0.29). The magnetization isotherms  $\sigma(H)$  measured for samples with  $0.25 \le x \le 0.27$  at temperatures of 77 and 300 K do not exhibit saturation. As seen from Fig. 4, which displays hysteresis loops, hysteresis is no longer seen in comparatively weak magnetic fields ( $H \sim 3-5$  kOe), but the magnetization does not saturate and continues to grow as the field increase. Such a situation is observed, for instance, in the gadolinium ferrite garnets and can be attributed to the positive component of magnetostriction appearing in strong fields [8]. The magnetization curves obtained on samples with  $x \sim 0.29$  are typical of ferromagnets, which is supported by the presence



**Fig. 4.** Field dependences of the magnetization of the  $Fe_xMn_{1-x}S$  system for different compositions *x* (a) at 300 K: (1) 0, (2) 0.05, and (3) 0.2; and (b) at 77 K: (1) 0.27 and (2) 0.29.

of a hysteresis loop. The same compositions exhibit the maximum colossal magnetoresistance ( $\sigma_H \sim -450\%$  in a field of 30 kOe at 50 K) [2].

#### 4. CONCLUSION

Thus, studies of the magnetic, electrical, and thermal properties of the  $Fe_xMn_{1-x}S$  solid solutions have revealed a sequence of phase transitions (at  $T_{c_1}$  and  $T_{c_2}$ ) in the compositions of the above sulfides exhibiting colossal magnetoresistance. The high-temperature phase ( $T > T_{c_2}$ ) is a paramagnetic metal. At  $T \sim T_{c_2}$ , a transition to the ferromagnetic state takes place, with the conduction character changing from metallic to semiconducting. The phase transition at  $T_{c_1}$ , associated possibly with lattice distortion, is accompanied by a strong increase in the magnetization and by a change in the conduction character of the semiconducting phase.

## ACKNOWLEDGMENTS

This study was supported by the Russian Foundation for Basic Research (project no. 00-02-81059 Bel 2000a) and, in part, by the project Eniseĭ-2002 (no. 02-02-97702).

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Translated by G. Skrebtsov